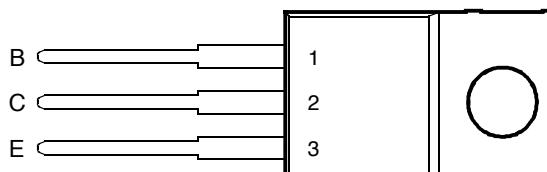


- 40 W at 25°C Case Temperature
- 1 A Continuous Collector Current
- 2 A Peak Collector Current
- 20 mJ Reverse-Energy Rating

! This series is obsolete and not recommended for new designs.

TO-220 PACKAGE
(TOP VIEW)

Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT
Collector-base voltage ($I_E = 0$)	V_{CBO}	350 400 450 500	V
Collector-emitter voltage ($I_B = 0$)	V_{CEO}	250 300 350 400	V
Emitter-base voltage	V_{EBO}	5	V
Continuous collector current	I_C	1	A
Peak collector current (see Note 1)	I_{CM}	2	A
Continuous base current	I_B	0.6	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)	P_{tot}	40	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)	P_{tot}	2	W
Unclamped inductive load energy (see Note 4)	$\frac{1}{2}LI_C^2$	20	mJ
Operating junction temperature range	T_j	-65 to +150	°C
Storage temperature range	T_{stg}	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds	T_L	260	°C

NOTE 1: This value applies for $t_p \leq 1$ ms, duty cycle $\leq 2\%$.

2. Derate linearly to 150°C case temperature at the rate of 0.32 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of: $L = 20$ mH, $I_{B(on)} = 0.4$ A, $R_{BE} = 100 \Omega$, $V_{BE(off)} = 0$, $R_S = 0.1 \Omega$, $V_{CC} = 20$ V.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = 30 \text{ mA}$ (see Note 5)	$I_B = 0$	TIP47 TIP48 TIP49 TIP50	250 300 350 400			V
I_{CES} Collector-emitter cut-off current	$V_{CE} = 350 \text{ V}$ $V_{CE} = 400 \text{ V}$ $V_{CE} = 450 \text{ V}$ $V_{CE} = 500 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	TIP47 TIP48 TIP49 TIP50			1 1 1 1	mA
I_{CEO} Collector cut-off current	$V_{CE} = 150 \text{ V}$ $V_{CE} = 200 \text{ V}$ $V_{CE} = 250 \text{ V}$ $V_{CE} = 300 \text{ V}$	$I_B = 0$ $I_B = 0$ $I_B = 0$ $I_B = 0$	TIP47 TIP48 TIP49 TIP50			1 1 1 1	mA
I_{EBO} Emitter cut-off current	$V_{EB} = 5 \text{ V}$	$I_C = 0$				1	mA
h_{FE} Forward current transfer ratio	$V_{CE} = 10 \text{ V}$ $V_{CE} = 10 \text{ V}$	$I_C = 0.3 \text{ A}$ $I_C = 1 \text{ A}$	(see Notes 5 and 6)	30 10		150	
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = 0.2 \text{ A}$	$I_C = 1 \text{ A}$	(see Notes 5 and 6)			1	V
V_{BE} Base-emitter voltage	$V_{CE} = 10 \text{ V}$	$I_C = 1 \text{ A}$	(see Notes 5 and 6)			1.5	V
h_{fe} Small signal forward current transfer ratio	$V_{CE} = 10 \text{ V}$	$I_C = 0.2 \text{ A}$	$f = 1 \text{ kHz}$	25			
$ h_{fel} $ Small signal forward current transfer ratio	$V_{CE} = 10 \text{ V}$	$I_C = 0.2 \text{ A}$	$f = 2 \text{ MHz}$	5			

NOTES: 5. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

resistive-load-switching characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS [†]			MIN	TYP	MAX	UNIT
t_{on} Turn on time	$I_C = 1 \text{ A}$	$I_{B(on)} = 0.1 \text{ A}$	$I_{B(off)} = -0.1 \text{ A}$		0.2		μs
t_{off} Turn off time	$V_{BE(off)} = -5 \text{ V}$	$R_L = 200 \Omega$	(see Figures 1 and 2)		2		μs

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PRODUCT INFORMATION

DECEMBER 1971 - REVISED SEPTEMBER 2002
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PARAMETER MEASUREMENT INFORMATION

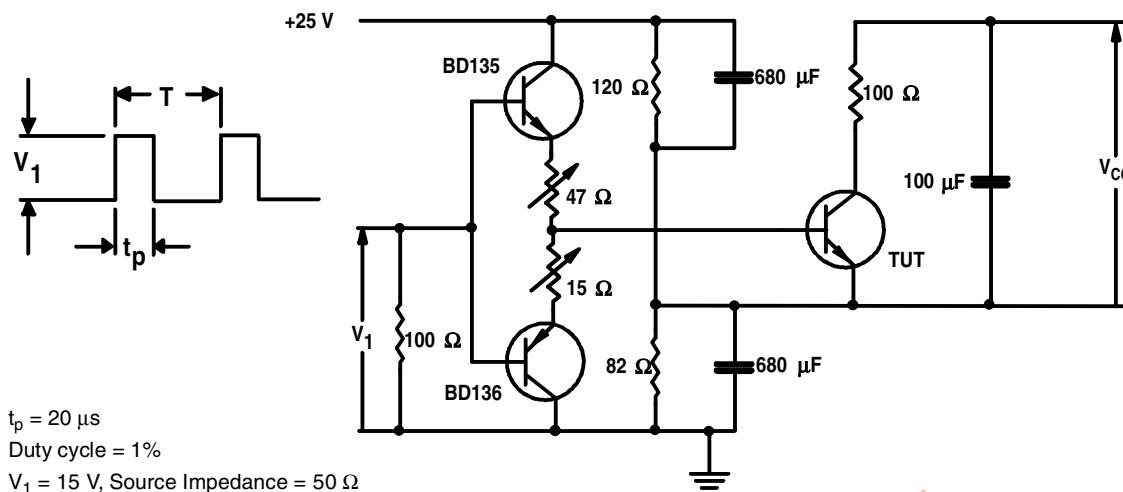


Figure 1. Resistive-Load Switching Test Circuit

A - B = t_d
B - C = t_r
E - F = t_f
D - E = t_s
A - C = t_{on}
D - F = t_{off}

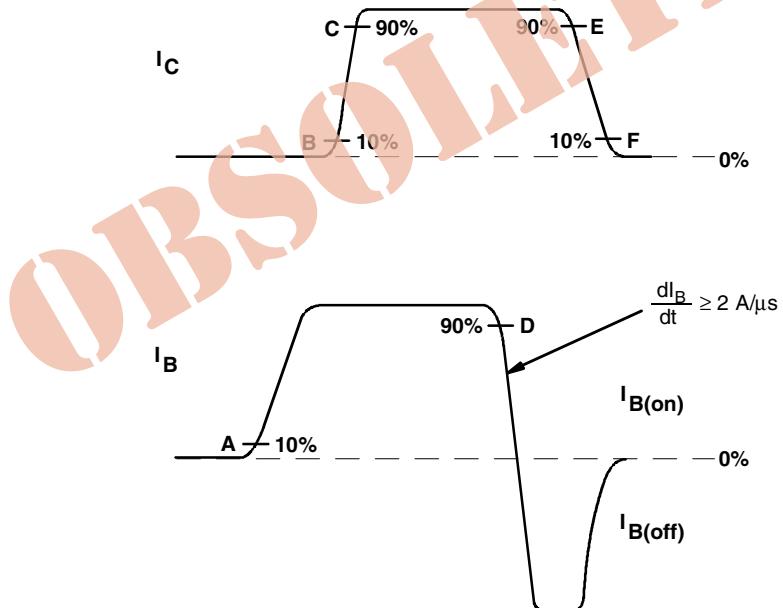


Figure 2. Resistive-Load Switching Waveforms

PRODUCT INFORMATION

TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN
vs
COLLECTOR CURRENT

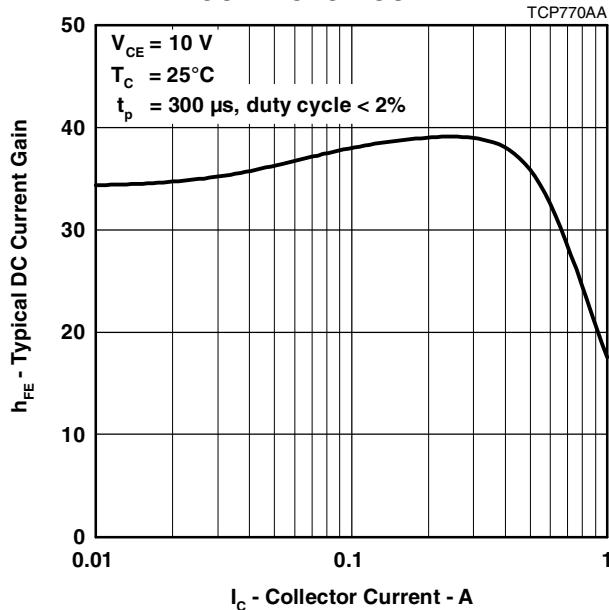


Figure 3.

COLLECTOR-EMITTER SATURATION VOLTAGE
vs
COLLECTOR CURRENT

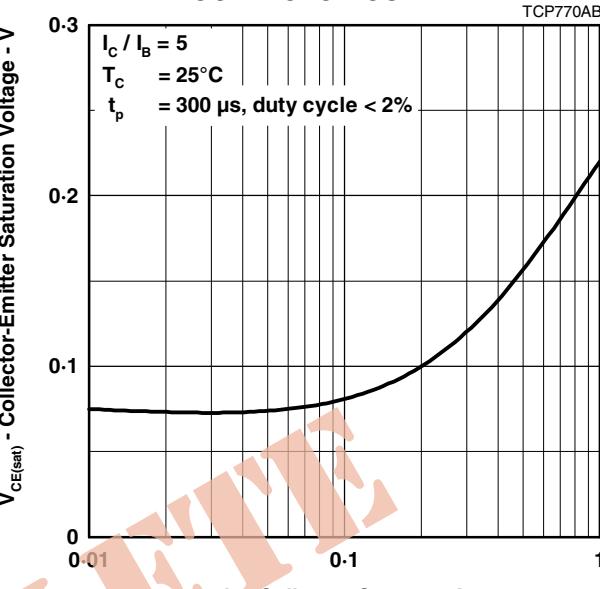


Figure 4.

BASE-EMITTER SATURATION VOLTAGE
vs
COLLECTOR CURRENT

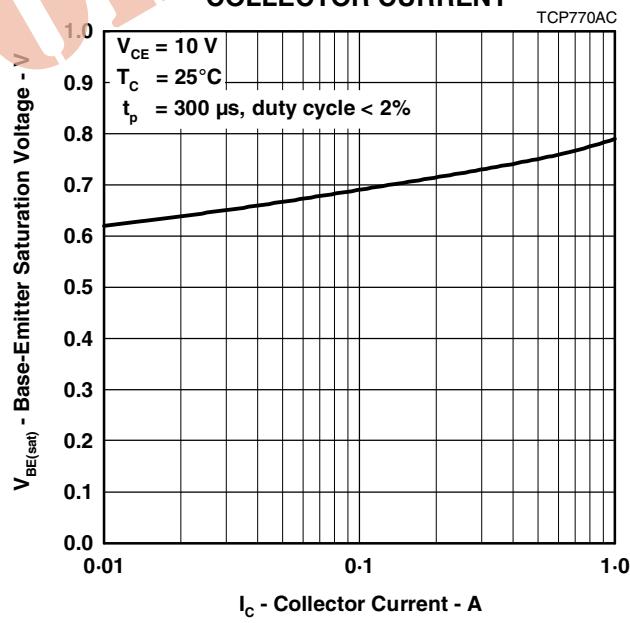


Figure 5.

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MAXIMUM SAFE OPERATING REGIONS

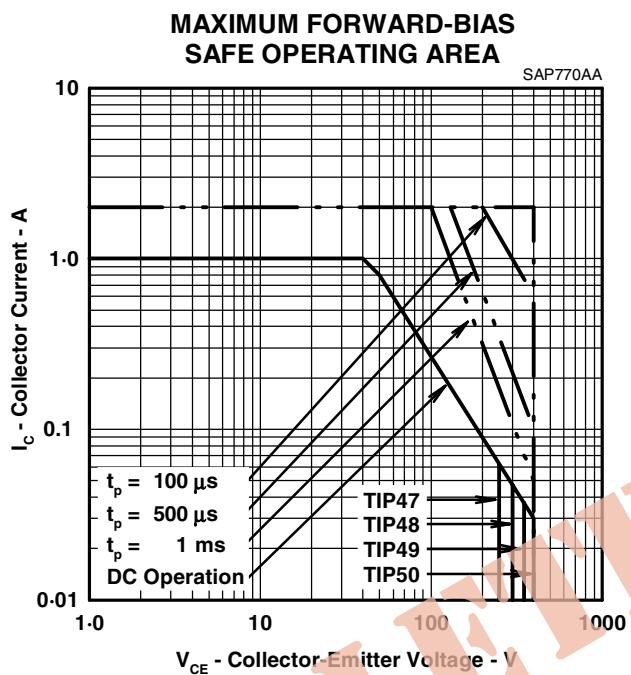


Figure 6.

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